



# Correction to: Carrier recombination and transport for Sb<sub>2</sub>Se<sub>3</sub>-based homojunction thin film solar cells

Donglou Ren<sup>1</sup> · Michel Cathelinaud<sup>1</sup> · Hongli Ma<sup>1</sup> · Xianghua Zhang<sup>1</sup>

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The authors would like to correct the acknowledgments section of their paper. It should read:

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- ✉ Donglou Ren  
donglou.ren@univ-rennes1.fr
  - ✉ Xianghua Zhang  
xiang-hua.zhang@univ-rennes1.fr

<sup>1</sup> ISCR (Institut des Sciences Chimiques de Rennes)-CNRS, UMR 6226, University of Rennes, 35000 Rennes, France